

Vishay Siliconix

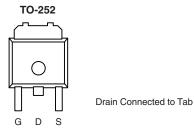
N-Channel 100-V (D-S) 175 °C MOSFET

PRODUCT SUMMARY					
V _{DS} (V)	R_{DS(on)} (Ω)	I _D (A)			
100	0.025 at V _{GS} = 10 V	40			
100	0.028 at V _{GS} = 4.5 V	38			

FEATURES

- TrenchFET[®] Power MOSFET
- 175 °C Maximum Junction Temperature
- 100 % Rg Tested





Top View

Ordering Information: SUD40N10-25 SUD40N10-25-E3 (Lead (Pb)-free)

G O S

N-Channel MOSFET

ABSOLUTE MAXIMUM RATINGS $T_A = 2$	25 °C, unless other	wise noted			
Parameter	Symbol	Limit	Unit		
Drain-Source Voltage		V _{DS}	100	- V	
Gate-Source Voltage	V _{GS}	± 20			
	T _C = 25 °C	1	40		
Continuous Drain Current $(T_J = 175 \ ^{\circ}C)^{b}$	T _C = 125 °C	I _D	23		
Pulsed Drain Current	I _{DM}	70	А		
Continuous Source Current (Diode Conduction)		۱ _S	40	1	
Avalanche Current	I _{AS}	40			
Single Pulse Avalanche Energy (Duty Cycle \leq 1 %)	L = 0.1 mH	E _{AS}	80	mJ	
	T _C = 25 °C	Р	136 ^b	W	
Maximum Power Dissipation	T _A = 25 °C	P _D -	3 ^a	vv	
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 175	°C	

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical	Maximum	Unit	
	t ≤ 10 s	R _{thJA}	15	18	°C/W	
Junction-to-Ambient ^a	Steady State		40	50		
Junction-to-Case		R _{thJC}	0.85	1.1		

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

b. See SOA curve for voltage derating.

* Pb containing terminations are not RoHS compliant, exemptions may apply.

SUD40N10-25

Vishay Siliconix



Parameter	Symbol	Test Conditions	Min.	Typ. ^a	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V _{DS}	$V_{GS} = 0 V, I_D = 250 \mu A$	100			V	
Gate Threshold Voltage	$V_{GS(th)}$ $V_{DS} = V_{GS}$, $I_D = 250 \ \mu A$		1.0		3.0	V	
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
		V _{DS} = 100 V, V _{GS} = 0 V			1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 125 ^{\circ}\text{C}$			50	μA	
		V_{DS} = 100 V, V_{GS} = 0 V, T_{J} = 175 °C			250		
On-State Drain Current ^b	I _{D(on)}	$V_{DS} = 5 V, V_{GS} = 10 V$	70			А	
		V _{GS} = 10 V, I _D = 40 A		0.02	0.025	5	
	Б	V_{GS} = 10 V, I _D = 40 A, T _J = 125 °C	0.05				
Drain-Source On-State Resistance ^b	R _{DS(on)}	V_{GS} = 10 V, I _D = 40 A, T _J = 175 °C			0.063	0.063 Ω	
		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 20 \text{ A}$		0.022	0.028		
Forward Transconductance ^b	9 _{fs}	V _{DS} = 15 V, I _D = 40 A		70		S	
Dynamic ^a							
Input Capacitance	C _{iss}			2400		pF	
Output Capacitance	C _{oss}	V_{GS} = 0 V, V_{DS} = 25 V, F = 1 MHz		290			
Reverse Transfer Capacitance	C _{rss}			120			
Total Gate Charge ^c	Qg			40	60		
Gate-Source Charge ^c	Q _{gs}	$V_{DS} = 50 \text{ V}, \text{ V}_{GS} = 10 \text{ V}, \text{ I}_{D} = 40 \text{ A}$		11		nC	
Gate-Drain Charge ^c	Q _{gd}			9		1	
Gate Resistance	R _g		1		3.5	Ω	
Turn-On Delay Time ^c	t _{d(on)}			8	13		
Rise Time ^c	t _r	V_{DD} = 50 V, R_L = 1.25 Ω		40	60		
Turn-Off Delay Time ^c	t _{d(off)}	$\text{I}_\text{D}\cong$ 40 A, V_GEN = 10 V, R_g = 2.5 Ω		15	25	ns	
Fall Time ^c	t _f			80	120		
Source-Drain Diode Ratings and Cha	racteristics 7	Γ _C = 25 °C		·	· ·		
Pulsed Current	I _{SM}				70	А	
Diode Forward Voltage ^b	V _{SD}	I _F = 40 A, V _{GS} = 0 V		1.0	1.5	V	
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 40 A, dl/dt = 100 A/μs		75	120	ns	

Notes:

a. Guaranteed by design, not subject to production testing. b. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

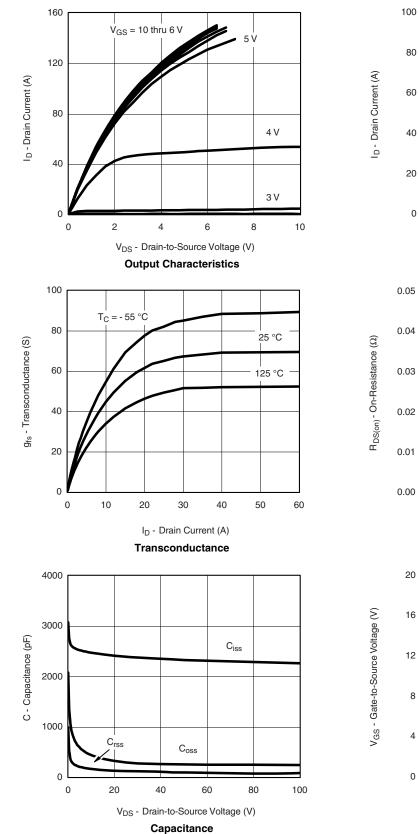
c. Independent of operating temperature.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



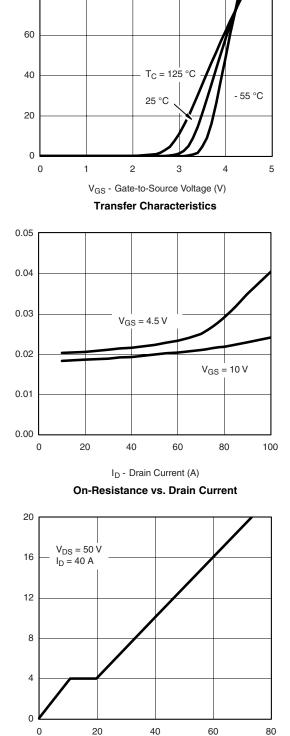
SUD40N10-25

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

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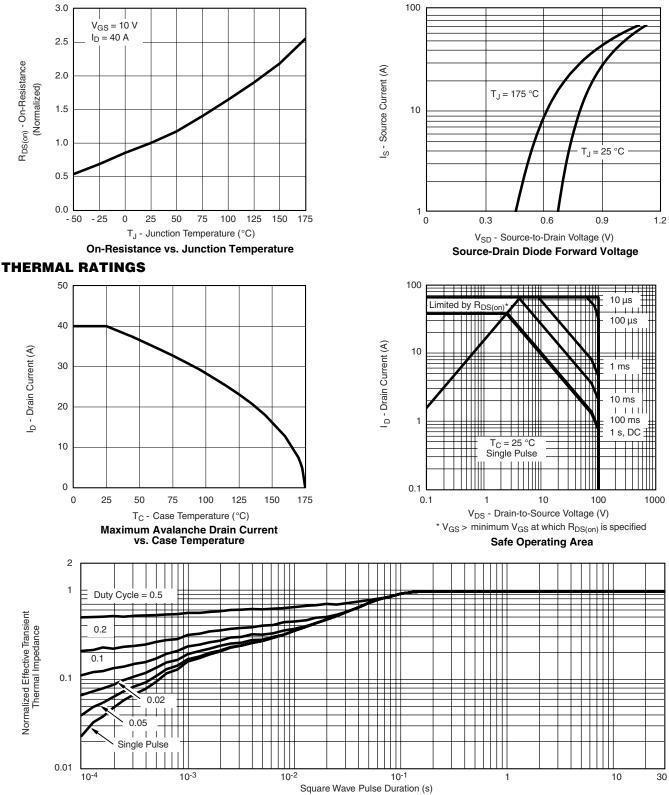
Qg - Total Gate Charge (nC)

Gate Charge

80

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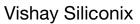
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

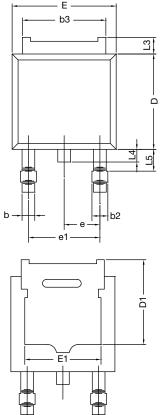
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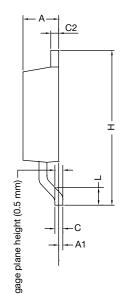
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TO-252AA Case Outline





	MILLIN	IETERS	INC	HES		
DIM.	MIN.	MAX.	MIN.	MAX.		
А	2.18	2.38	0.086	0.094		
A1	-	0.127	-	0.005		
b	0.64	0.88	0.025	0.035		
b2	0.76	1.14	0.030	0.045		
b3	4.95	5.46	0.195	0.215		
С	0.46	0.61	0.018	0.024		
C2	0.46	0.89	0.018	0.035		
D	5.97	6.22	0.235	0.245		
D1	4.10	-	0.161	-		
Е	6.35	6.73	0.250	0.265		
E1	4.32	-	0.170	-		
Н	9.40	10.41	0.370	0.410		
е	2.28	2.28 BSC		0.090 BSC		
e1	4.56	4.56 BSC		BSC		
L	1.40	1.78	0.055	0.070		
L3	0.89	1.27	0.035	0.050		
L4	-	1.02	-	0.040		
L5	1.01	1.52	0.040	0.060		
ECN: T16- DWG: 534	0236-Rev. P, ⁻ 7	16-May-16				

Notes

• Dimension L3 is for reference only.



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RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

Return to Index



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